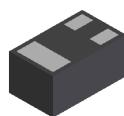


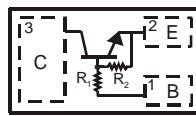
## Features

- Epitaxial Planar Die Construction
- Ultra-Small Leadless Surface Mount Package
- Ideally Suited for Automated Assembly Processes
- Lead Free By Design/RoHS Compliant (Note 1)**
- "Green" Device (Note 2)**
- Qualified to AEC-Q101 Standards for High Reliability

Part Number	R1 (NOM)	R2 (NOM)
DDTC123JLP	2.2K	47K
DDTC143ZLP	4.7K	47K
DDTC114YLP	10K	47K



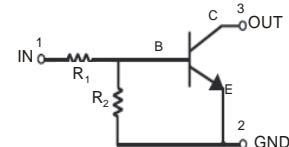
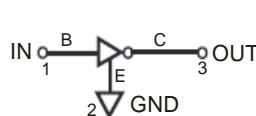
Bottom View



Package Pin Out Configuration

## Mechanical Data

- Case: DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: Collector Dot (See Diagram and Marking Information)
- Terminals: Finish — NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 6
- Ordering Information: See Page 6
- Weight: 0.0009 grams (approximate)



Device Schematics

## Maximum Ratings

$\text{@T}_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	P/N	Symbol	Value	Unit
Supply Voltage		$V_{CC}$	50	V
Input Voltage	DDTC123JLP	$V_{IN}$	-5 to +12	V
	DDTC143ZLP		-5 to +30	
	DDTC114YLP		-5 to +40	
Output Voltage	DDTC123JLP	$I_o$	100	mA
	DDTC143ZLP		100	
	DDTC114YLP		70	
Maximum Collector Current		$I_{C(MAX)}$	100	mA

## Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	$P_D$	250	mW
Power Deration above 25 °C	$P_{der}$	2	mW/°C
Thermal Resistance, Junction to Ambient Air (Note 3) (Equivalent to one heated junction of NPN)	$R_{\theta JA}$	500	°C/W
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	°C

Notes:

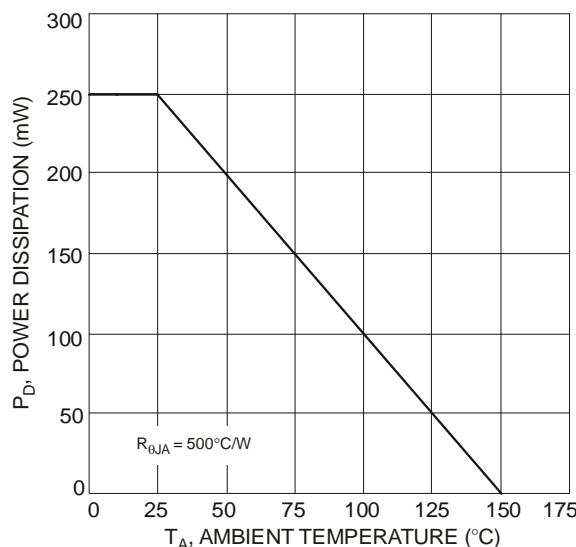
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
- Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on page 6 or our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

**Electrical Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	P/N	Symbol	Min	Typ	Max	Unit	Test Condition	
<b>Off Characteristics (Note 4)</b>								
Collector-Base Breakdown Voltage		$V_{(\text{BR})\text{CBO}}$	50	—	—	V	$I_C = 10\mu\text{A}, I_E = 0$	
Collector-Emitter Breakdown Voltage *		$V_{(\text{BR})\text{CEO}}$	50	—	—	V	$I_C = 2\text{mA}, I_B = 0$	
Emitter-Base Breakdown Voltage *		$V_{(\text{BR})\text{EBO}}$	4.5	—	—	V	$I_E = 50\mu\text{A}, I_C = 0$	
Collector Cutoff Current *		$I_{\text{CEX}}$	—	—	0.5	$\mu\text{A}$	$V_{\text{CE}} = 50\text{V}, V_{\text{EB}(\text{OFF})} = 3.0\text{V}$	
Base Cutoff Current ( $I_{\text{BEX}}$ )		$I_{\text{BL}}$	—	—	0.5	$\mu\text{A}$	$V_{\text{CE}} = 50\text{V}, V_{\text{EB}(\text{OFF})} = 3.0\text{V}$	
Collector-Base Cut Off Current		$I_{\text{CBO}}$	—	—	0.5	$\mu\text{A}$	$V_{\text{CB}} = 50\text{V}, I_E = 0$	
Collector-Emitter Cut Off Current, $I_{\text{O}(\text{OFF})}$		$I_{\text{CEO}}$	—	—	0.5	$\mu\text{A}$	$V_{\text{CE}} = 50\text{V}, I_B = 0$	
Emitter-Base Cut Off Current		$I_{\text{EBO}}$	—	—	0.5	$\text{mA}$	$V_{\text{EB}} = 5\text{V}, I_C = 0$	
Input-Off Voltage		$V_{\text{I}(\text{OFF})}$	—	—	0.5	V	$V_{\text{CE}} = 5\text{V}, I_C = 100\mu\text{A}$	
<b>On Characteristics (Note 4)</b>								
Base-Emitter Turn-On Voltage*	DDTC123JLP	$V_{\text{BE}(\text{ON})}$	—	—	0.85	V	$V_{\text{CE}} = 5\text{V}, I_C = 2\text{mA}$	
	DDTC143ZLP		—	—	0.85			
	DDTC114YLP		—	—	0.95			
Base-Emitter Saturation Voltage*	DDTC123JLP	$V_{\text{BE}(\text{SAT})}$	—	—	0.98	V	$I_C = 10\text{mA}, I_B = 1\text{mA}, V_{\text{CE}} = 5\text{V}$	
	DDTC143ZLP		—	—	0.998			
	DDTC114YLP		—	—	0.98			
Input-On Voltage		$V_{\text{I}(\text{ON})}$	1.1	—	—	V	$V_O = 0.3\text{V}, I_C = 5\text{mA}$	
Input Current	DDTC123JLP	$I_I$	—	—	7.2	mA	$V_I = 5\text{V}$	
	DDTC143ZLP		—	—	1.5			
	DDTC114YLP		—	—	7.2			
DC Current Gain		$h_{\text{FE}}$	50	—	—	—	$V_{\text{CE}} = 5\text{V}, I_C = 1\text{mA}$	
			70	—	—			
			125	—	—			
			150	—	—			
			180	—	—			
Collector-Emitter Saturation Voltage		$V_{\text{CE}(\text{SAT})}$	—	—	0.15	V	$I_C = 10\text{mA}, I_B = 1\text{mA}$	
			—	—	0.2	V	$I_C = 50\text{mA}, I_B = 5\text{mA}$	
Output On Voltage (Same as $V_{\text{CE}(\text{SAT})}$ )		$V_{\text{O}(\text{ON})}$	—	—	0.3	—	$I_O = 2.5\text{mA}, I_C = 50\text{mA}$	
Input Resistor +/-30%		$\Delta R_1$	-30	—	30	%	—	
Resistor Ratio		$\Delta (R_2/R_1)$	-20	—	-20	%	—	
<b>Small Signal Characteristics</b>								
Transition Frequency (gain bandwidth product)		$f_T$	—	250	—	MHz	$V_{\text{CE}} = 10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$	

\*Guaranteed by design

Notes: 4. Short duration pulse test used to minimize self-heating effect.

 Pulse Test: Pulse width,  $t_p < 300\text{ }\mu\text{s}$ , Duty Cycle,  $d < 0.02$ 
**Typical Characteristics Curves** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

 Fig. 1 Power Dissipation vs. Ambient Temperature  
 (Note 3)

**Characteristics Curves of DDTC123JLP**

④  $T_A = 25^\circ\text{C}$  unless otherwise specified

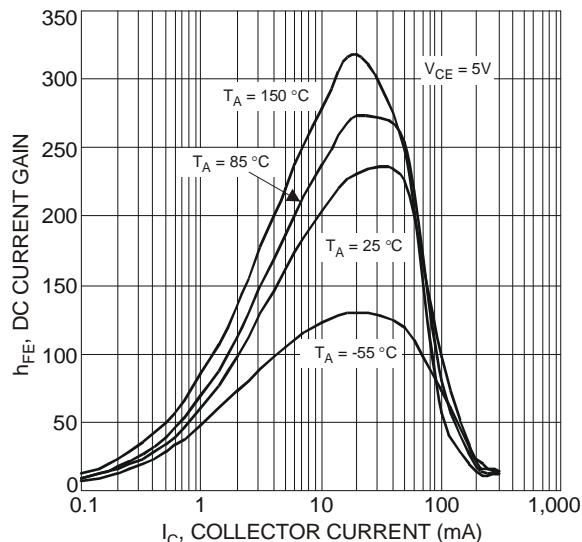


Fig. 2 Typical DC Current Gain vs. Collector Current

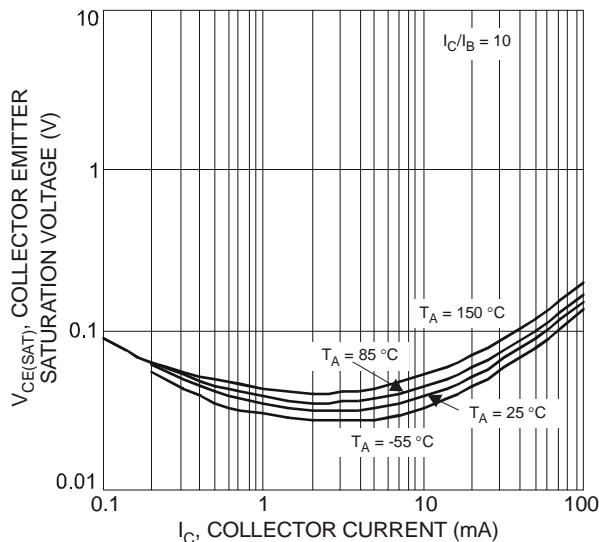


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

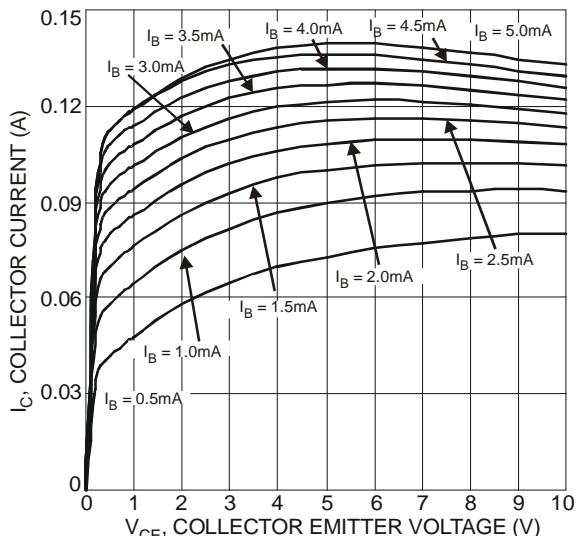


Fig. 4 Typical Collector Current vs. Collector Emitter Voltage

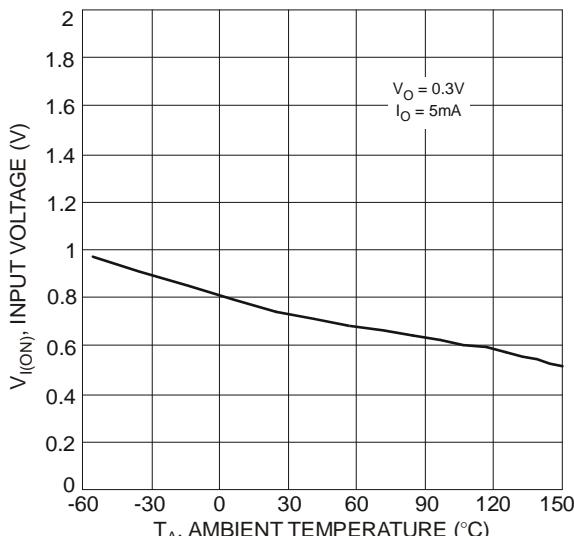


Fig. 5 Typical Input Voltage vs. Ambient Temperature

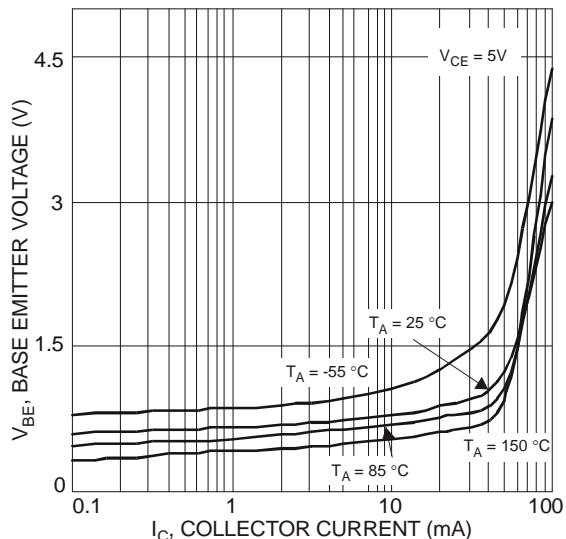


Fig. 6 Typical Base Emitter Voltage vs. Collector Current

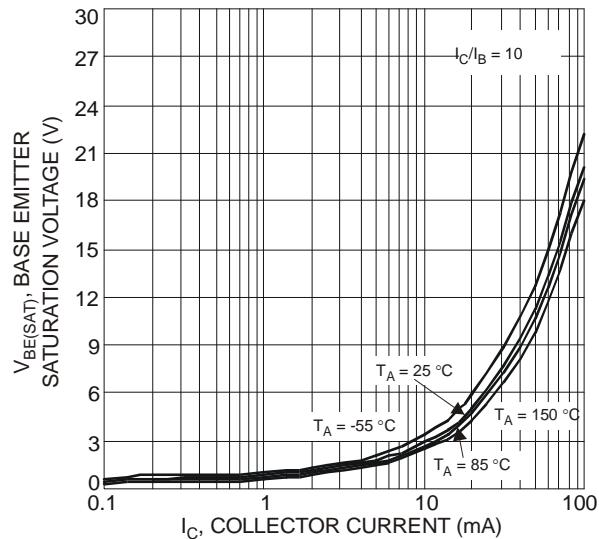


Fig. 7 Typical Base Emitter Saturation Voltage vs. Collector Current

**Characteristics Curves of DDTC143ZLP**

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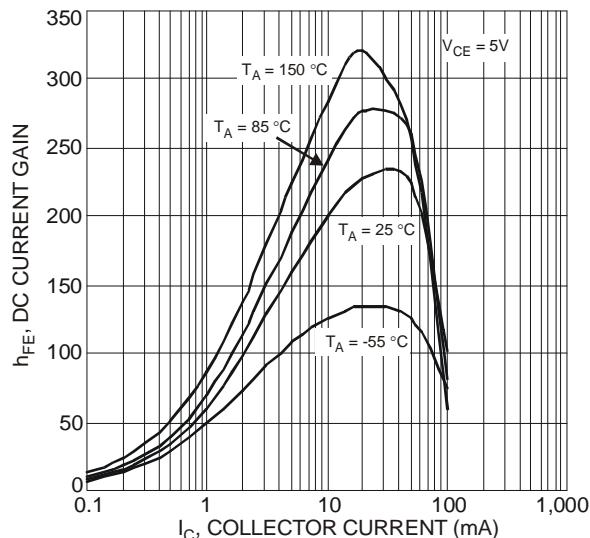


Fig. 8 Typical DC Current Gain vs. Collector Current

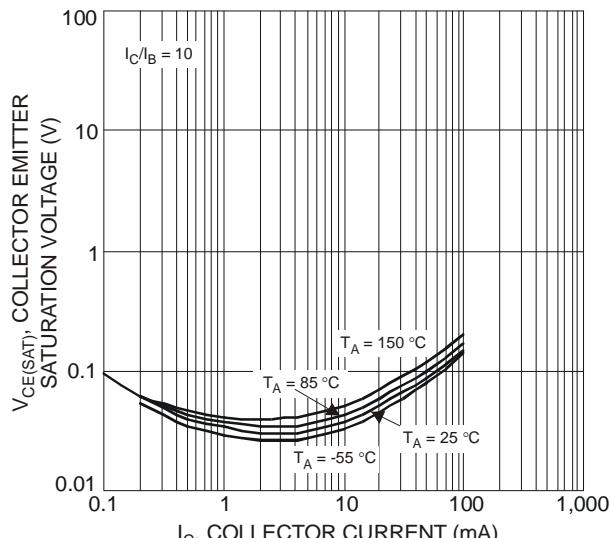


Fig. 9 Typical Collector Emitter Saturation Voltage vs. Collector Current

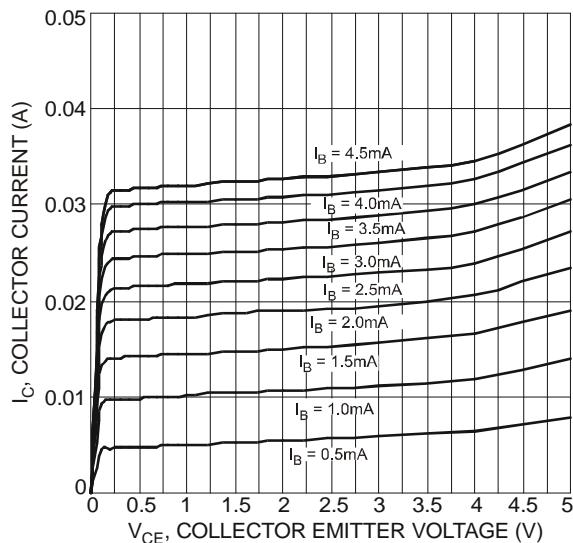


Fig. 10 Typical Collector Current vs. Collector Emitter Voltage

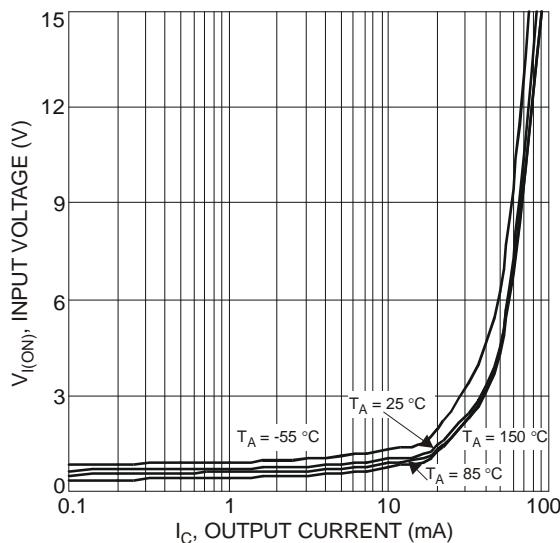


Fig. 11 Typical Input Voltage vs. Output Current

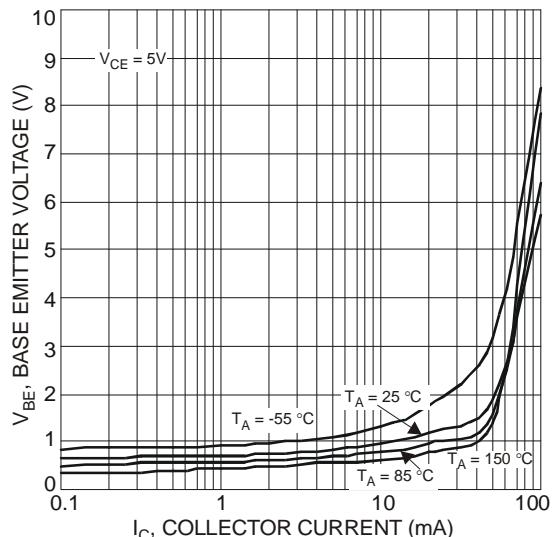


Fig. 12 Typical Base Emitter Voltage vs. Collector Current

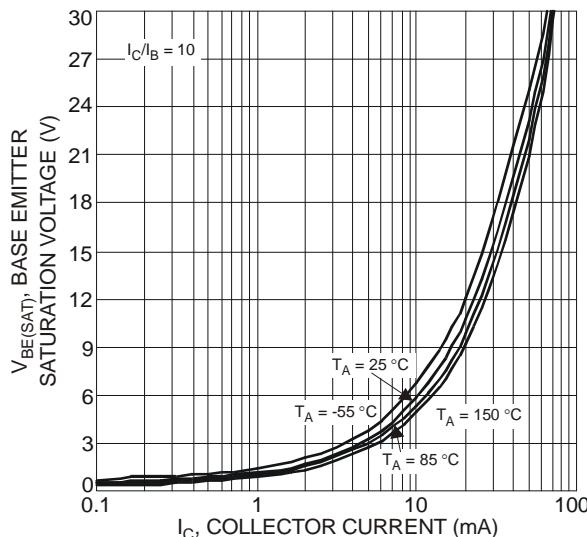


Fig. 13 Typical Base Emitter Saturation Voltage vs. Collector Current

**Characteristics Curves of DDTC114YLP**

$\text{T}_A = 25^\circ\text{C}$  unless otherwise specified

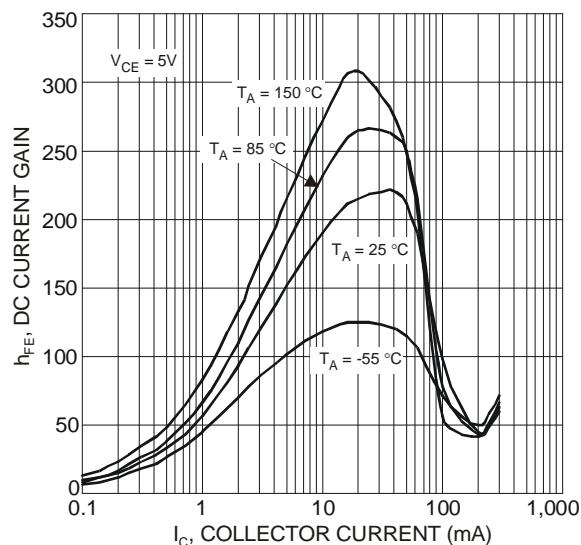


Fig. 14 Typical DC Current Gain vs. Collector Current

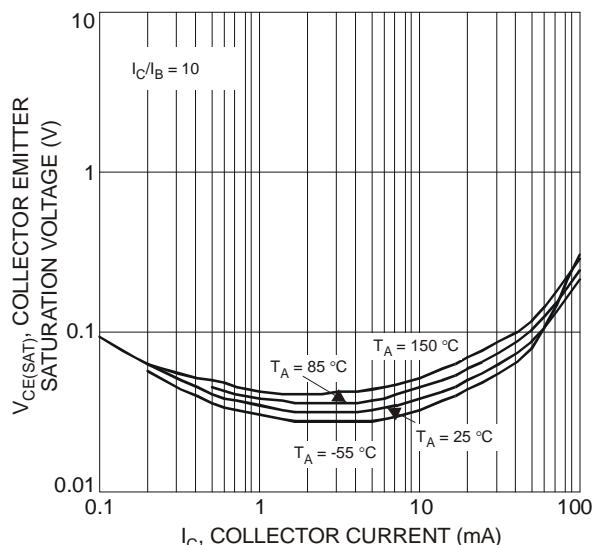


Fig. 15 Typical Collector Emitter Saturation Voltage vs. Collector Current

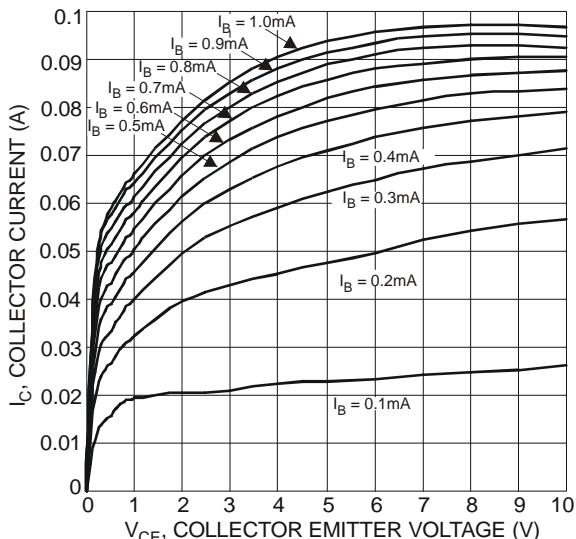


Fig. 16 Typical Collector Current vs. Collector Emitter Voltage

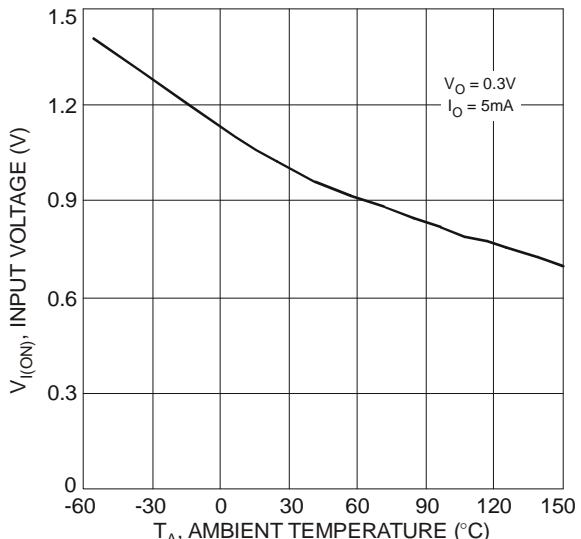


Fig. 17 Typical Input Voltage vs. Ambient Temperature

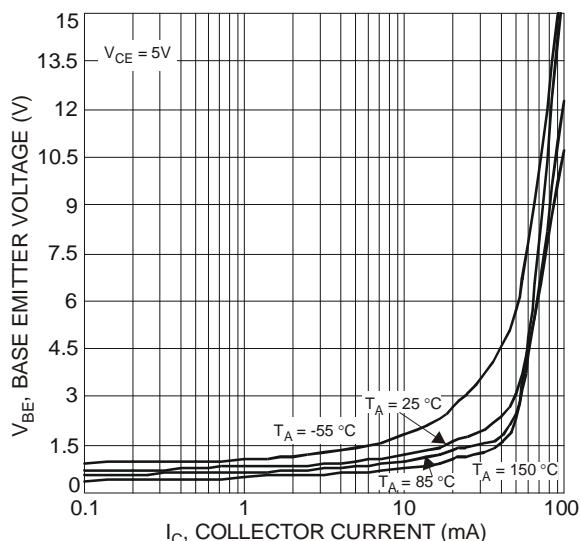


Fig. 18 Typical Base Emitter Voltage vs. Collector Current

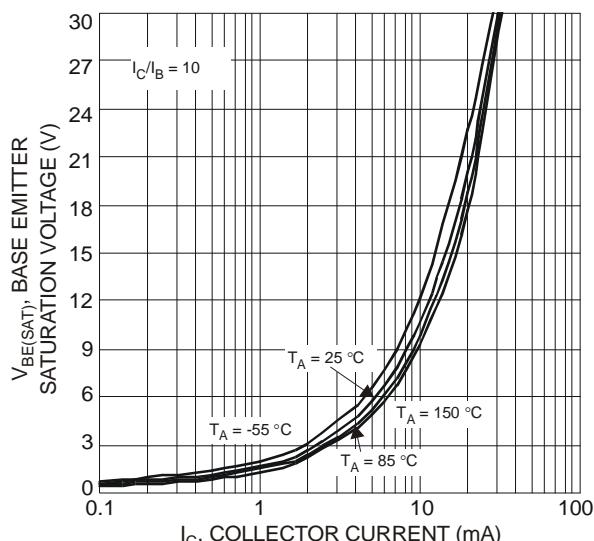


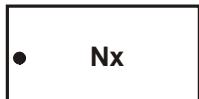
Fig. 19 Typical Base Emitter Saturation Voltage vs. Collector Current

## Ordering Information (Note 5)

Part Number	Case	Packaging
DDTC123JLP-7	DFN1006-3	3000/Tape & Reel
DDTC143ZLP-7	DFN1006-3	3000/Tape & Reel
DDTC114YLP-7	DFN1006-3	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



Nx = Product Type Marking Code:

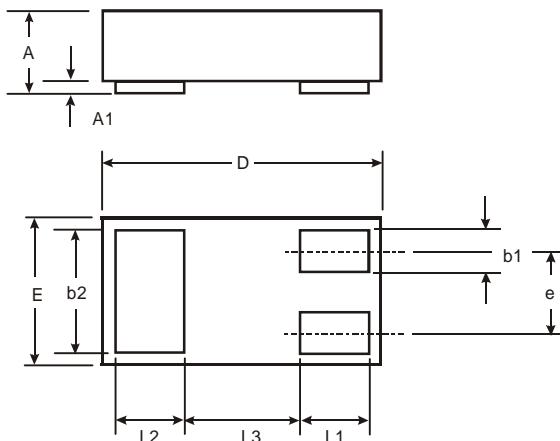
DDTC123JLP = N0

DDTC143ZLP = N1

DDTC114YLP = N2

Dot Denotes Collector, Pin 3

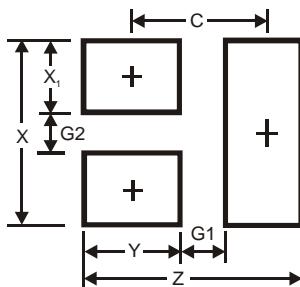
## Package Outline Dimensions



DFN1006-3			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0	0.05	0.03
b1	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	—	—	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	—	—	0.40

All Dimensions in mm

## Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
X	0.7
X1	0.25
Y	0.4
C	0.7

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